Field-induced spin polarization in the lightly Cr-substituted layered antiferromagnet NiPS₃

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Tuning magnetic properties in layered magnets is an important route to realize novel phenomenon related to two-dimensional (2D) magnetism. Recently, tuning antiferromagnetic (AFM) properties through substitution and intercalation techniques has been widely studied in MPX_3 compounds. Interesting phenomena, such as diverse AFM structures and even the signatures of ferrimagnetism, have been reported. However, long-range ferromagnetic (FM) ordering has remained elusive. In this work, we explored the magnetic properties of the Cr-substituted NiPS₃. We found that Cr substitution is extremely efficient in controlling spin orientation in NiPS₃. Our study reveals a field-induced spin polarization in lightly (9%) Cr-substituted NiPS₃, which is likely attributed to the attenuation of AFM interactions and magnetic anisotropy due to Cr doping. Our work provides a possible strategy to achieve FM phase in AFM MPX_3 , which could be useful for investigating 2D magnetism as well as potential device applications.

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I. INTRODUCTION

Tuning magnetic properties in two-dimensional (2D) magnetic materials provides opportunity for deeper understanding of low-dimensional magnetism as well as enhance their feasibility for potential applications in next-generation devices [1–24]. Magnetic properties in layered magnetic materials have been found to be efficiently tunable by doping [25-56]. Particularly, introducing guest atoms in van der Waals (vdW) magnets can control the spin orientation, which leads to novel magnetic phenomenon arising from 2D magnetism. Metal thiophosphates MPX_3 (M = metal such asMn, Fe, Ni, etc; X = chalcogen S and Se) compounds are such vdW magnets. Extensive efforts such as substitutions of metal (M) [25–40,56,57] or chalcogen (X) [46–50,57], and interlayer intercalation [53–55,58] have been adopted to tune the antiferromagnetic (AFM) ground state in MPX_3 . Various AFM structures have been obtained through M and X substitutions [25–40,46–50]. So far, whether ferromagnetism can be induced through substitution is still under debate. Theoretical efforts both supporting [59] and disapproving [60] this route have been reported. Experimentally, so far neither M nor X substitutions has been successful in stabilizing long-range ferromagnetic (FM) ordering in MPX_3 . In addition to substitution, interlayer intercalation is another doping strategy which is generally expected to cause charge doping. It has been proposed that ferromagnetism in MPX_3 can be induced by charge doping [61,62]. However, intercalating various guest species in MPX_3 has been reported to result in ferrimagnetism [53–55], yet ferromagnetism remains elusive.

Stabilizing ferromagnetism in MPX_3 is highly desired. First, it makes the study of 2D magnetism more accessible. This is because, due to the absence of net magnetization, direct probe of AFM ordering in atomically thin limit is challenging by using nanoscale magnetic characterization techniques such as scanning single-spin magnetometry [63], magneto-optical Kerr effect microscopy [1,2], polar reflective magnetic circular dichroism [64], and x-ray magnetic dichroism [65]. In addition, recent studies have predicted that FM phases of MPX₃ are not only limited within the boundary of 2D magnetism but could be extended to topological physics [59,66]. Hence, the rise of ferromagnetism in MPX_3 would provide a rare platform for investigating the interplay between magnetism and band topology in 2D. Furthermore, breaking time-reversal symmetry by ferromagnetism may induce other exotic phenomena, especially in heterostacking of FM-layered material and other quantum materials such as superconductors and topological materials, which require 2D FM materials.

This work focuses on tuning AFM properties by substituting metal ions. Metal-ion substitution in MPX_3 has led to a series of polymetallic "mixed" $(M_1)_{1-x}(M_2)_xPX_3$ compounds, where M_1 and M_2 represent the original and substituted metal elements, respectively [25–40,56,67–70].

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The previous substitution studies have mainly focused on three representative compounds, $MnPX_3$, $FePX_3$, and NiP X_3 . Various metal ions such as Mn²⁺ [28–30,33,36,38], Fe^{2+} [28–30,32,33,37,40], Co^{2+} [39], Ni^{2+} [32,36–38,40], Cu^{2+} [71], Zn^{2+} [25–27,34,56,67], Mg^{2+} [69], and Cd^{2+} [68,70] have been adopted for substitution. Interestingly, Cr substitution in MPX₃ is still lacking despite recent developments in various Cr-based vdW magnets [1,2,4,8-10,12,14-18,51,52]. In this work, we have investigated Cr-substituted NiPS₃, and revealed field-induced spin polarization in 9% Cr-substituted NiPS₃. Such sensitive tuning in Cr-substituted NiPS₃ is likely attributed to weakening of AFM exchange and magnetic anisotropy due to Cr substitution that enables magnetic field to polarize Cr moments together with the partial polarization of some surrounding Ni ions. Our study offers a possible route to establish ferromagnetism in MPX_3 , providing a platform to study 2D magnetism as well as an opportunity to develop magnetic materials-based nextgeneration devices.

II. EXPERIMENT

The various $Ni_{1-x}Cr_xPS_3$ ($0 \le x \le 0.09$) single crystals used in this work were synthesized by a chemical vapor transport method using I_2 as the transport agent. Elemental powders with desired ratios were sealed in a quartz tube and heated in a two-zone furnace with a temperature gradient from 750 to 550 °C for a week. The elemental compositions and crystal structures of the obtained crystals were examined by energy-dispersive x-ray spectroscopy (EDS) and x-ray diffraction (XRD), respectively. Magnetization measurements were performed in a physical property measurement system (PPMS, Quantum Design).

III. RESULTS AND DISCUSSION

In MPX₃, the AFM ordering has been found to be extremely robust against perturbation from external magnetic field. The field-dependent studies of three representative compounds, MnPS₃, FePS₃, and NiPS₃, have revealed that a high magnetic field is needed to reorient moments of the two AFM sublattices into a spin-flop (SF) phase, which is manifested as the metamagnetic transition in the isothermal magnetization measurements under a strong field of $\mu_0 H \approx 4$, 6, and 35 T applied along the magnetic easy axes at $T \approx 5$ K in MnPS₃ [72,73], NiPS₃ [38], and FePS₃ [74], respectively. After the SF transition, further applying the field leads to a linear increase of magnetization with no sign of saturation up to 20 and 9 T at $T \approx 5$ K in MnPS₃ [72] and NiPS₃ [38], respectively. In fact, a very high field up to \sim 40 T at a similar temperature is needed to saturate magnetization in FePS₃ [74]. This is suggestive of strong AFM interactions in MPX_3 , which requires a high magnetic field to achieve a fully polarized FM phase.

In contrast, the magnetic moments in some layered AFM compounds can be easily polarized by applying a magnetic field. For example, Cr-based magnets such as CuCrP₂S₆ [75,76], CrPS₄ [77], CrCl₃ [78], and CrSBr [79] all exhibit AFM to field-polarized FM transitions at relatively low magnetic field below 8 T. Despite distinct crystal

lattices, the Cr moments in these layered compounds are ordered in an A-type AFM configuration, which is characterized by antiferromagnetically coupled FM layers [77,80–83]. The interlayer AFM exchange between Cr moments is accompanied by essentially isotropic magnetic ordering because of small single-ion anisotropy for Cr^{3+} (d^3) ion arising due to a quenched orbital moment [80,81]. Such weak AFM coupling and/or small magnetic anisotropy has been attributed to a field-driven AFM to FM transition at relatively low field in Cr-based AFM compounds [76,77,80,82]. This raises a natural question if Cr-based MPX_3 compounds could feature a similar low-field FM state.

The studies of MPX_3 compounds consisting of early 3dtransition metals such as Ti, V, and Cr have been very limited. So far, only $V_x PS_3$ (x = 0.78 [84,85], 0.9 [86], and 1 [87]) and CrPSe₃ [88] have been reported. Indeed, our efforts in synthesizing the previously unreported CrPS₃ only yield another known compound CrPS₄. The difficulty in growing CrPS₃ has been proposed to originate from the destabilized P-P dimerization in P₂S₆ bipyramid structure unit, which is caused by a weaker Cr-S covalency in comparison to the metal-sulfur covalency in late transition-metal based MPX_3 (M = Fe to Znin the periodic table) compounds [89]. With the suppression of P-P dimerization, the P₂S₆ bipyramid unit changes valence from 4- to a nominal 6- in the ionic bonding approach, so that the divalent character for metal ion enhances to a higher valence state such as Cr³⁺ and eventually favors the formation of CrPS₄ rather than CrPS₃ [89]. This scenario is in line with the fact that Cr ion usually forms +3 valence in Cr-based vdW magnetic materials [75-77,79,90]. Similar scenario of +3 metal valence is also seen in another early transitionmetal based MPX₃ compound V_xPS_3 (x = 0.78 [84,85] and 0.9 [86]), where V^{2+} and V^{3+} ions coexist and distribute randomly, giving rise to vacancies at the V sites [84–86].

Given the difficulty in direct synthesis for pristine CrPS₃, we switched to a different approach, i.e., partial substitution of Cr in NiPS₃. In our study, we found that this is also challenging in comparison to other divalent metal-ion substitutions [36–38,40,69,70]. Despite that various Cr contents in the source materials for synthesis have been tried, we were only able to introduce up to the highest 9% Cr in NiPS₃ [Fig. 1(a)]. This is in stark contrast to a much higher substitutions of Co [39], Cu [71], Mg [69], and Cd [68,70], and even complete substitutions of Mn [30,36,38] and Fe [37,40] in NiPS₃. Such difficulty in doping Cr in NiPS₃ can be attributed to a similar reason that hinders the formation of pristine CrPS₃ phase as stated above.

Successful Cr doping has been demonstrated by composition analysis using EDS [Fig. 1(a)]. Given such a low amount of Cr, the compositions were determined after confirming homogeneous elemental phase in multiple locations of the crystals. We found that the highest Cr content can be obtained by our chemical vapor transport technique is 9% (x = 0.09), which limited our study to lightly doping regime. Nevertheless, as will be shown below, even light Cr-doping can induce strong modifications in magnetic properties in NiPS₃. To better understand the effect of Cr doping on magnetic properties, clarifying the doping scenario, i.e., substituting Ni or intercalating to the vdw gap, is important. The composition analysis by EDS quantitative analysis implies a substitution scenario

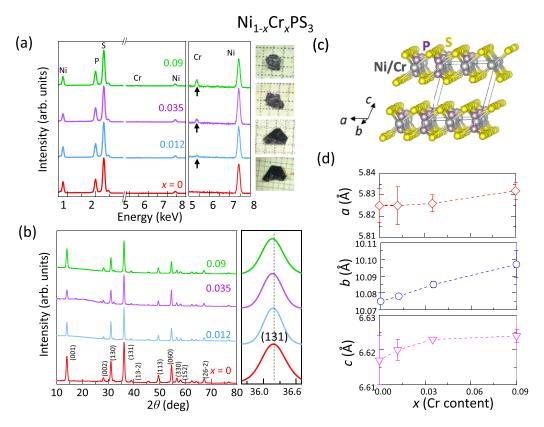


FIG. 1. (a) Energy-dispersive x-ray spectroscopy (EDS) along with crystal images. The right panel shows the increased EDS spectrum intensity for Cr as denoted by the black arrows. (b) X-ray diffraction (XRD) result for Cr-substituted NiPS₃, Ni_{1-x}Cr_xPS₃ ($0 \le x \le 0.09$). Right panel in (b) shows evolution of XRD peak in which the dashed lines are to guide the eye. (c) The crystal structure of Ni_{1-x}Cr_xPS₃ ($0 \le x \le 0.09$). (d) Composition dependence of lattice parameters a, b, and c in Ni_{1-x}Cr_xPS₃ ($0 \le x \le 0.09$).

without any metal vacancies, which is further supported by our structural analysis. The powder XRD pattern obtained by grounding the single crystals is shown in Fig. 1(b). Cr substitution for Ni up to 9% (the highest Cr content obtained in this work) does not induce any structure transition. Only a tiny low-angle peak shift with Cr substitution is observed, as shown in the right panel of Fig. 1(b), which indicates a small expansion of NiPS3 lattice. More structural information has been obtained via Rietveld refinement. We found that a structural model [presented in Fig. 1(c)] assuming a substitution scenario and without vacancy sites nicely reproduces the powder XRD patterns. The extracted lattice constants are shown in Fig. 1(d), which reveals slight and systematic increases in all three lattice parameters a, b, and c upon Cr substitution. Such increase is consistent with the tiny lattice expansion due to partial substitution of Ni²⁺ by larger ion Cr²⁺. On the other hand, an intercalation scenario can also expand the lattice. Generally, intercalating to the vdW gap generally causes a much stronger increase in c axis as compared to a and b, which has been observed in an earlier intercalation study on organicion intercalated NiPS₃ [58]. However, such anisotropic lattice expansion is very different from the nearly isotropic lattice expansion along all three axes in our samples, as shown in Fig. 1(d).

In addition to identifying a substitution scenario for Cr doping, the above composition and structure analyses also demonstrate the absence of metal vacancies, which supports a +2 valence for the substituted Cr ions. Clarifying the Cr

valence is important because it determines the *d*-orbital occupancies that affect the magnetic exchange interaction. In addition, the presence of vacancies can cause local structure distortions that affect local magnetism, creating additional complexity in understanding the mechanisms of the modification of magnetism by doping.

In NiPS₃, although the light metal substitution does not significantly modify the lattice type, it still influences the magnetic properties. For example, substituting 5% Mn [38] and 10% Fe [37] can efficiently control the magnetism in NiPS₃. To investigate the effects of Cr substitution on magnetic properties of NiPS₃, we measured the field M(H) and temperature M(T) dependences of magnetization for our lightly substituted $Ni_{1-x}Cr_xPS_3$ samples. As shown in M(H) measurements under in-plane [H//ab], Fig. 2(a)] and out-of-plane $[H\perp ab]$, Fig. 2(b)] magnetic fields at T = 2 K, substituting up to 9% Cr for Ni has substantial effect on field dependence of magnetization, resulting in systematic enhancement of magnetization with Cr substitution. In addition, the SF transition is strongly modified in Cr-substituted NiPS3, which will be discussed below. The tunable magnetism in NiPS₃ is also demonstrated by the composition dependence of Néel temperature $T_{\rm N}$. Figure 3(a) presents the temperature dependence of susceptibility under in-plane (H//ab, blue) and out-of-plane $(H\perp ab, blue)$ red) magnetic fields of $\mu_0 H = 0.1$ T. To obtain the precise $T_{\rm N}$, we calculated the derivative $d\chi/dT$ for susceptibility data and used their peak position to define T_N [inset, Fig. 3(a)], which has been widely used in previous studies [36,37,40,49].

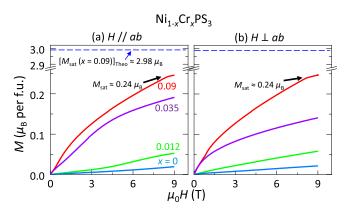


FIG. 2. Field dependence of magnetization for $Ni_{1-x}Cr_xPS_3$ ($0 \le x \le 0.09$) samples at T=2 K under (a) in-plane (H|ab) and (b) out-of-plane ($H \perp ab$) magnetic fields. The black arrows denote saturation of magnetization for the x=0.09 sample. The dashed lines denote the theoretical saturated magnetization value of $2.98\mu_B$ for the x=0.09 sample, if all metal-ion moments are polarized.

The extracted $T_{\rm N}$ for the parent compound NiPS₃ is found to be 155 K, consistent with the reported values [38,91]. As summarized in Fig. 4 (top panel), in Ni_{1-x}Cr_xPS₃, the $T_{\rm N}$ significantly drops from 155 K for x=0 to 34 K up on only 9% Cr substitution.

Highly sensitive magnetism to Cr substitution in NiPS₃ is further supported by the evolution of SF transition with Cr substitution. NiPS₃ exhibits a metamagnetic transition at an in-plane magnetic field of 6 T [Fig. 3(b)], which is characterized by a clear upturn (shown by blue arrows) in isothermal magnetizations M(H) at T=2 K. Such metamagnetic transition under an in-plane field in NiPS3 has recently been discovered and was attributed to a SF transition [38], consistent with the nearly in-plane magnetic moment orientation for Ni ions in this compound [91]. The SF behavior of NiPS₃ is significantly modified upon Cr substitution. As shown in Fig. 3(b), with increasing Cr content x, the SF transition, which occurs under an in-plane field (H//ab), is strongly suppressed, as manifested by the less-obvious magnetization upturn and reduced SF field ($H_{\rm SF}$) from $\mu_0 H_{\rm SF} \approx 6$ T (for x = 0) to 0.6 T (for x = 0.09) at T = 2 K. Furthermore, the SF transition is observed only under in-plane field (blue arrow) in x = 0 - 0.035 samples, while it appears under both in-plane (blue arrow; $\mu_0 H_{\rm SF} \approx 0.6$ T) and out-of-plane (red arrow; $\mu_0 H_{\rm SF} \approx 0.8$ T) magnetizations in the x = 0.09 sample. The tuning of SF transition is summarized in Fig. 4 (middle panel), which suggests the moment reorientation upon Cr substitution as will be discussed later.

In NiPS₃, the SF state is driven by external magnetic field along the magnetic easy axis, which rotates the Ni moments and causes weak FM component arising from the uncompensated canted moments [38]. Applying field exceeding $H_{\rm SF}$ and up to 9 T is unable to polarize such canted moments in NiPS₃ (x=0) (Fig. 2), which is consistent with the previous report [38]. Also, although substituting Cr for Ni suppresses the $H_{\rm SF}$ in the x=0.012 sample (Fig. 4), its magnetization does not saturate up to 9 T. However, this scenario appears to change completely with further increasing Cr amount. For x=0.035 and 0.09 samples, the SF transitions occur at much

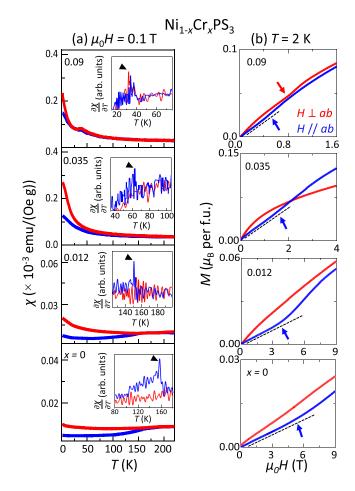


FIG. 3. (a) Temperature dependence of susceptibility for Ni_{1-x}Cr_xPS₃ (0 $\leq x \leq$ 0.09) samples under in-plane (H|ab, blue) and out-of-plane ($H\perp ab$, red) magnetic fields of $\mu_0H=0.1$ T. Insets: Temperature dependence of derivative susceptibility $d\chi/dT$. The peak of $d\chi/dT$ denotes $T_{\rm N}$, which is denoted by black triangles. (b) Field dependence of magnetization for Ni_{1-x}Cr_xPS₃ (0 $\leq x \leq$ 0.09) samples at T=2 K under out-of-plane ($H\perp ab$, red) and in-plane (H|ab, blue) magnetic fields. The red and blue arrows in (b) denote spin-flop field under $H\perp ab$ and H|ab magnetic fields, respectively. The dashed lines are to guide the eye.

lower H_{SF} , and a moment polarization behavior featuring sublinear magnetization starts to occur at higher fields. In particular, a clear kink near 8 T can be observed in both inplane [Fig. 2(a)] and out-of-plane [Fig. 2(b)] magnetizations of the x = 0.09 sample, as indicated by the black arrows in the figures, which indicates spin polarization. Above the saturation field of $H_{\text{sat}} \sim 8$ T at T=2 K for x=0.09, the magnetizations for both field directions attain a value ~0.24 $\mu_{\rm B}$ per f.u. (formula units) ([Figs. 2(a) and 2(b)]. Considering the moment of Ni²⁺ of $2.82\mu_B$ and the moment of Cr²⁺ of $4.60\mu_{\rm B}$, substituting 9% Ni with Cr results in a theoretical magnetic moment $\sim 2.98 \mu_{\rm B}$ per f.u, as denoted by the blue dashed lines in Fig. 2. The observed much lower saturation moment indicates that a full spin polarization is not achieved. Such spin-polarization behavior can be understood in terms of the polarization of only Cr and the surrounding Ni ions. Substitution of a Cr²⁺ for a Ni²⁺ in an AFM lattice would

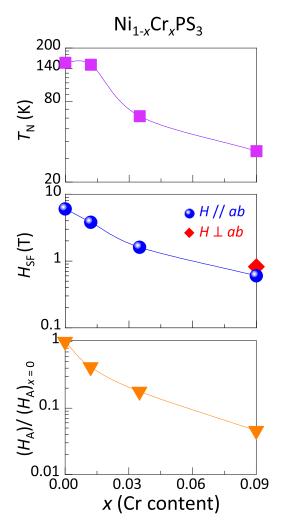


FIG. 4. Doping dependence of Néel temperature $(T_{\rm N})$, spin-flop field $(H_{\rm SF})$, and the ratio of effective magnetic anisotropy field $(H_{\rm A})$ of Ni_{1-x}Cr_xPS₃, normalized to $H_{\rm A}$ for the x=0 sample.

result in net magnetic moment of μ (Cr²⁺) – μ (Ni²⁺) = $4.60\mu_B$ – $2.82\mu_B$ = $1.78\mu_B$. Therefore, the 9% Cr²⁺ substitution should yield a net moment of $\sim 0.16\mu_B$ per f.u. This, together with the partial polarization of some surrounding Ni ions, shows a total net moment of $0.24\mu_B$ per f.u. is reasonable.

To understand the effect of Cr substitution, we performed systematic isothermal magnetization measurements at various temperatures for the x = 0.09 sample. As shown in Figs. 5(a) and 5(b), the in-plane and out-of-plane isothermal magnetizations display a saturation-like behavior above $H_{\rm sat} \sim 8$ T at T=2 K. The saturation field H_{sat} is gradually reduced with rising temperature. The reduction of H_{sat} can be ascribed to the additional thermal energy upon heating that assists moment polarization under lower field. Although increasing temperature favors moment polarization, high temperature also randomizes magnetic moments and attenuates the correlation between them. Therefore, the SF transition is no longer clearly visible, and the field-dependent isothermal magnetization gradually evolves from a sublinear to a linear field dependence above 30 K. In fact, this temperature also corresponds to the AFM ordering temperature T_N , which is

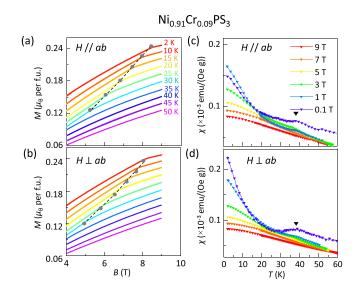


FIG. 5. (a),(b) Field dependence of magnetization for Ni_{0.91}Cr_{0.09}PS₃ sample at various temperatures from 2 to 50 K under (a) in-plane (H||ab) and (b) out-of-plane $(H \perp ab)$ magnetic fields. The dashed lines denote the evolution of saturation field $(H_{\rm SF})$ with temperature. (c), (d) Temperature dependence of susceptibility for Ni_{0.91}Cr_{0.09}PS₃ sample at various (c) in-plane $(H \mid ab)$ and (d) out-of-plane $(H \perp ab)$ magnetic fields from 0.1 to 9 T. The black triangles denote $T_{\rm N}$.

suppressed from 155 K in pristine NiPS₃ [38] to 34 K in this 9% Cr substituted sample, as mentioned earlier. Compared to other metal-ion substitution in NiPS₃ such as Mn substitution for Ni [38]. Cr substitution is much more efficient in suppressing magnetic ordering temperature. Figures 5(c) and 5(d) show temperature-dependent in-plane and out-ofplane magnetic susceptibilities, respectively, for the identical x = 0.09 sample measured under various magnetic fields from 0.1 to 9 T. At 0.1 T, $T_{\rm N} \approx 34$ K characterized by a weak susceptibility peak, and more precisely in differential susceptibility $d\chi/dT$ [inset of Fig. 3(a)] shifts to a lower temperature upon increasing magnetic field, and eventually becomes unobservable down to T = 2 K above 3 T. Such suppression of AFM ordering by relatively low field for Cr-substituted NiPS₃ is in stark contrast to the field-independent T_N for pristine NiPS₃ [38], implying weakened AFM coupling due to Cr substitution. The weakening of AFM interaction is also in line with the field-driven spin polarization at relatively low field in x = 0.09 sample, as seen in other Cr-based antiferromagnets [76,77,80,82].

In addition to weak AFM interactions, a low magnetic anisotropy has also been proposed to be a possible reason for the field-induced moment polarization in some Cr-based AFM compounds [76,77,80,82]. The strength of magnetic anisotropy can be evaluated from the evolution of SF behavior or vice versa. One way to clarify it is the comparison of SF transition in (Mn,Ni,Fe)PS₃, in which H_{SF} increases with enhancing single-ion anisotropy from MnPS₃ to FePS₃ in the order MnPS₃ < NiPS₃ < FePS₃ (4, 6, and 35 T, respectively, at $T \sim 5$ K) [38,73,74]. Furthermore, the modification of magnetic anisotropy in MPX_3 compounds by metal substitution has been reported to tune SF transition [27,38]. For example,

in Zn-substituted MnPS₃ [27], 20% Zn substitution for Mn reduces H_{SF} by half, which has been ascribed to the weakening of magnetic anisotropy due to diluting Mn magnetic lattice by nonmagnetic Zn substitution. Such tunable SF transition in MnPS₃ is expected given negligible single-ion anisotropy for Mn ($A \approx 0.0086$ meV) [92]. For NiPS₃, owing to the more pronounced $A \approx 0.3 \text{ meV}$ for Ni [93], the tuning of SF transition could be more difficult than MnPS₃. However, surprisingly, here we found that the SF transition in NiPS₃ is sensitive to very light Cr substitution. In fact, similar highly sensitive SF transition to light substitution has also been discovered in our earlier study on Mn-substituted NiPS₃ [38]. As mentioned earlier, the SF field H_{SF} monotonically decreases with increasing Cr content x in $Ni_{1-x}Cr_xPS_3$ (Fig. 4). These observations suggest reduced magnetic anisotropy by Cr substitution in NiPS₃, which is supported by the evolution of the effective magnetic anisotropy field. The spin-flop field can be approximately expressed as $H_{\rm SF} \approx \sqrt{2H_{\rm E}H_{\rm A}}$, where $H_{\rm E}$ and $H_{\rm A}$ are the effective fields characterizing magnetic exchange and anisotropy, respectively [27,94]. So, the anisotropy field $H_{\rm A}$ can be estimated by $H_{\rm A} \approx (H_{\rm SF})^2/(H_{\rm E})$. The spin-flop field $H_{\rm SF}$ can be evaluated from the field-dependent magnetization, and effective exchange field $H_{\rm E}$ can be assessed by ordering temperature $T_{\rm N}$. From the temperature-dependent susceptibility [Fig. 3(a)] and field-dependent magnetization [Fig. 3(b)] measurements, we have extracted the composition dependence of magnetic ordering temperature T_N and spin-flop field $H_{\rm SF}$ at 2K, as summarized in Fig. 4. With Cr substitution up to 9%, $T_{\rm N}$ is suppressed by a factor of 4.6 from \sim 155 to \sim 34 K, while $H_{\rm SF}$ decreases by a factor of 10 from 6 to 0.6 T. This leads to a significant suppression of the anisotropy field H_A : H_A in the x = 0.9 sample being reduced to only 5% of that of the undoped sample. Such result indicates Cr substitution is very efficient in suppressing the magnetic anisotropy. In addition, reduced magnetic anisotropy is also supported by the evolution of low-field (below H_{SF}) magnetization. As shown in Fig. 3(b), increasing Cr content x gradually suppresses anisotropy between in-plane and out-of-plane magnetizations below H_{SF} . The reduced magnetic anisotropy with Cr substitution generates more controllable moment orientation that eventually polarizes towards field direction as seen in x = $0.09 \text{ in Ni}_{1-x} Cr_x PS_3$.

In MPX_3 , tuning magnetic anisotropy can modify the moment orientations. As mentioned earlier, the weakening of magnetic anisotropy on increasing Cr substitution implies the rotation of moments from the nearly in-plane orientation in pristine NiPS₃ towards the out-of-plane direction, as illustrated in the schematic in Fig. 6. Increasing Cr content x causes the spin to rotate away from the basal plane. Because the SF transition in AFM compounds is driven by magnetic field component along the magnetic easy axis, the absence of the SF transition under out-of-plane magnetic field in x =0.012 and 0.036 samples [Fig. 4(a)] implies that the canted moments should not deviate too much from the basal plane with less amount of Cr substitution, which is similar to pristine NiPS₃. Further increasing the Cr content to 9% (i.e., x =0.09), weak but clear metamagnetic transitions appear with the application of both in-plane and out-of-plane magnetic fields [Fig. 3(b)], which is in stark contrast to metamagnetic transition observed only along the magnetic easy axis in

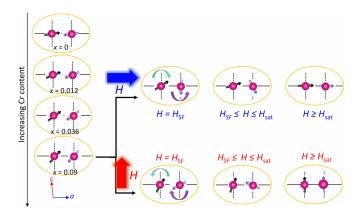


FIG. 6. Schematic of evolution of magnetic moment orientations with Cr substitution up to 9% in NiPS₃. This schematic further displays evolution of magnetic moments under in-plane (H||ab) and out-of-plane $(H\perp ab)$ magnetic fields in Ni_{0.91}Cr_{0.09}PS₃ sample.

Cr-based antiferromagnets [75–79]. Such distinct SF behavior in the x=0.09 sample might be attributed to strongly canted moments. Having said that, the slightly lower in-plane $H_{\rm SF}$ in x=0.09 sample [Fig. 4(b)] suggests that the moments could still be tilted slightly towards the ab plane. With such canted AFM ordering, both in-plane and out-of-plane fields can reorient moments to a SF state above some $H_{\rm SF}$, as shown in Fig. 6. Further increasing the field (i.e., $H_{\rm SF} \leqslant H \leqslant H_{\rm sat}$) will gradually polarize the canted moments above a saturation field $H_{\rm sat}$.

In addition, the suppression of magnetic anisotropy is also important in magneto-optical studies, which have recently demonstrated the strong interplay between light-matter interactions and magnetism in MPX_3 [95–98]. For example, in NiPS₃, a novel coherent spin-orbit entangled excitonic state stabilized by AFM order [95] as well as correlation between emitted photon and spins have been reported [96]. Such coupling can lead to an all-optical control of magnetic anisotropy in NiPS₃ [97]. Therefore, lowering magnetic anisotropy could facilitate a more optical control of magnetism in this material family. Furthermore, a strong correlation between field-driven moment reorientation and emitted photon has been demonstrated in NiPS₃ [96]; however, this phenomenon has been observed at very high magnetic field around 14 T. In our work, the moment reorientation is found to occur under much lower magnetic field around 0.6 T in the 9% Cr-substituted NiPS₃ sample [as shown by spin-flop transition in magnetization measurement in Fig. 3(b)], which could make the optical studies under magnetic field more convenient and magnetooptical phenomenon more accessible. Hence, this work also offers a promising platform to tune light-matter interactions for photonic processes in layered magnets.

The above results demonstrate that Cr substitution can strongly tune the magnetic properties in NiPS₃. We also want to emphasize that the lattice of NiPS₃ barely changes upon Cr substitution [Figs. 1(b) and 1(d)]. Such sensitivity to light Cr substitution (a few percent) in NiPS₃ is quite interesting and demands further theoretical and experimental investigations to clarify the complete mechanism. Furthermore, our study sheds light on a few important questions that have so far remained elusive. For example, why do all the Cr-based

antiferromagnets exhibit similar magnetic properties such as low-field spin-flop transition followed by spin polarization at high field? How can one incorporate more Cr into MPX₃ lattice? Furthermore, another previously largely overlooked question in many doped systems is that, will those dopants form possible long-range or short-range ordering to further affect the properties? Answering those questions could be important for future material development and implementations, and doped MPX₃ systems provide an excellent platform to investigate and address those important question.

In conclusion, we have studied the previously unexplored Cr-substituted NiPS₃ compounds. In contrast to other metalion substitutions such as Mn, Fe, Co, Cu, and Zn, Cr substitution in NiPS₃ is found to be very challenging and light substitution up to only a few percent can be realized. We found that Cr substitution can significantly alter the magnetic properties of NiPS₃. Such doping effects in NiPS₃ can be understood in terms of tuning magnetic exchange and anisotropy, and eventually results in a field-driven spin po-

larization in the Ni_{0.91}Cr_{0.09}PS₃ sample. This finding suggests that Cr doping could be a possible route to achieve FM state in *MPX*₃. Furthermore, our work also provides a platform to study 2D magnetism as well as magneto-optics in *MPX*₃ and design nanodevices based on magnetic materials for spintronics applications.

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